

## Features

- Operate from 1.65V to 5.5V
- Inputs Accept Voltages to 5.5V
- High Noise Immunity
- Low Power Dissipation
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

## General Description

The NL17SZ125DFT2G-TP is a single bus buffer/line driver with 3-state output. When the output enable ( $\overline{OE}$ ) is high the output will be disabled. In contrast, when the  $\overline{OE}$  is low, true data will pass from A input to the Y output. This device has power-down protective circuit to prevent the device from destruction when it is powered down.

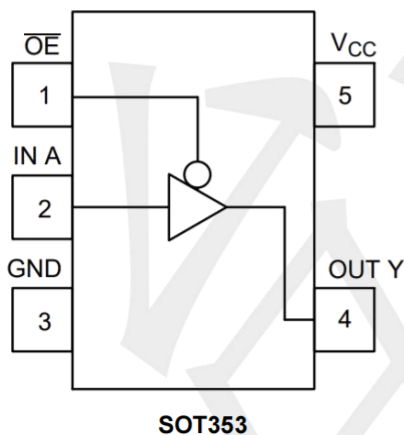
## Applications

- AV Receiver
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- Embedded PC
- Personal Digital Assistant(PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive(SSD): Client and Enterprise
- Wireless Headset, Keyboard, and Mouse

## Logic Diagram



## Pin Configuratio



## Function Table

INPUT( $\overline{OE}$ )	INPUT(A)	OUTPUT(Y)
L	L	L
L	H	H
H	X	Z

Note: H: HIGH voltage level; L: LOW voltage level; X=don't care; Z=high-impedance OFF-state.

## Absolute Maximum Ratings

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT
Supply Voltage	V <sub>CC</sub>		-0.5 ~ +6.5	V
Input Voltage	V <sub>IN</sub>		-0.5 ~ +6.5	V
Output Voltage	V <sub>OUT</sub>	Enable mode	-0.5 ~ V <sub>CC</sub> + 0.5	V
		Disable mode	-0.5 ~ +6.5	V
		Power-down mode	-0.5 ~ +6.5	V
VCC or GND Current	I <sub>CC</sub>	Output in the Power-off state	±100	mA
Continuous Output Current	I <sub>OUT</sub>	V <sub>OUT</sub> =0~V <sub>CC</sub>	±50	mA
Input Clamp Current	I <sub>IK</sub>	V <sub>IN</sub> <0	-50	mA
Output Clamp Current	I <sub>OK</sub>	V <sub>OUT</sub> <0	-50	mA
Storage Temperature Range	T <sub>STG</sub>		-65 ~ +150	°C
Junction to Ambient	θ <sub>JA</sub>	SOT353	280	°C/W

**Note:** Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

## Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V <sub>CC</sub>	Operating	1.65	--	5.5	V
Input Voltage	V <sub>IN</sub>		0	--	5.5	V
Output Voltage	V <sub>OUT</sub>	V <sub>CC</sub> =1.65V ~ 5.5V; Enable mode	0	--	V <sub>CC</sub>	V
		V <sub>CC</sub> =1.65V ~ 5.5V; Disable mode	0	--	5.5	V
		V <sub>CC</sub> =0V; Power-down mode	0	--	5.5	V
Input Transition Rise or Fall Rate	t <sub>R</sub> /t <sub>F</sub>	V <sub>CC</sub> =1.65V ~ 2.7V	--	--	20	ns/V
		V <sub>CC</sub> =2.7V ~ 5.5V	--	--	10	ns/V
Operating Temperature	T <sub>A</sub>		-40	--	125	°C

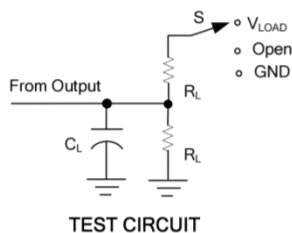
**Electrical Characteristics** (unless otherwise specified)

PARAMETER	SYMBOL	TEST Conditions	TA=25°C			TA=-40°C~+125°C			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
High-Level Input Voltage	V <sub>IH</sub>	V <sub>CC</sub> =1.65V ~ 1.95V	0.65×V <sub>CC</sub>	--	--	0.65×V <sub>CC</sub>	--	--	V
		V <sub>CC</sub> =2.3V ~ 2.7V	1.7	--	--	1.7	--	--	V
		V <sub>CC</sub> =3V ~ 3.6V	2	--	--	2	--	--	V
		V <sub>CC</sub> =4.5V ~ 5.5V	0.7×V <sub>CC</sub>	--	--	0.7×V <sub>CC</sub>	--	--	V
Low-Level Input Voltage	V <sub>IL</sub>	V <sub>CC</sub> =1.65V ~ 1.95V	--	--	0.35×V <sub>CC</sub>	--	--	0.35×V <sub>CC</sub>	V
		V <sub>CC</sub> =2.3V ~ 2.7V	--	--	0.7	--	--	0.7	V
		V <sub>CC</sub> =3V ~ 3.6V	--	--	0.8	--	--	0.8	V
		V <sub>CC</sub> =4.5V ~ 5.5V	--	--	0.35×V <sub>CC</sub>	--	--	0.35×V <sub>CC</sub>	V
High-Level Output Voltage	V <sub>OH</sub>	V <sub>CC</sub> =1.65 ~ 5.5V, I <sub>OH</sub> =-100μA	V <sub>CC</sub> -0.1	--	--	V <sub>CC</sub> -0.1	--	--	V
		V <sub>CC</sub> =1.65V, I <sub>OH</sub> =-4mA	1.2	--	--	0.95	--	--	V
		V <sub>CC</sub> =2.3V, I <sub>OH</sub> =-8mA	1.9	--	--	1.7	--	--	V
		V <sub>CC</sub> =2.7V, I <sub>OH</sub> =-12mA	2.2	--	--	1.9	--	--	V
		V <sub>CC</sub> =3.0V, I <sub>OH</sub> =-24mA	2.3	--	--	2	--	--	V
		V <sub>CC</sub> =4.5V, I <sub>OH</sub> =-32mA	3.8	--	--	3.4	--	--	V
Low-Level Output Voltage	V <sub>OL</sub>	V <sub>CC</sub> =1.65 ~ 5.5V, I <sub>OL</sub> =100μA	--	--	0.1	--	--	0.1	V
		V <sub>CC</sub> =1.65V, I <sub>OL</sub> =4mA	--	--	0.45	--	--	0.7	V
		V <sub>CC</sub> =2.3V, I <sub>OL</sub> =8mA	--	--	0.3	--	--	0.45	V
		V <sub>CC</sub> =3.0V, I <sub>OL</sub> =16mA	--	--	0.4	--	--	0.6	V
		V <sub>CC</sub> =3.0V, I <sub>OL</sub> =24mA	--	--	0.55	--	--	0.8	V
		V <sub>CC</sub> =4.5V, I <sub>OL</sub> =32mA	--	--	0.55	--	--	0.8	V
Input Leakage Current	I <sub>I(LEAK)</sub>	V <sub>CC</sub> =0 ~ 5.5V, V <sub>IN</sub> =5.5V or GND	--	±0.1	±5	--	--	±5	μA
Power OFF Leakage Current	I <sub>OFF</sub>	V <sub>CC</sub> =0V, V <sub>IN</sub> or V <sub>OUT</sub> =5.5V	--	±0.1	±10	--	--	±10	μA
Quiescent Supply Current	I <sub>Q</sub>	V <sub>CC</sub> =1.65 ~ 5.5V, V <sub>IN</sub> =V <sub>CC</sub> or GND, I <sub>OUT</sub> =0A	--	±0.1	10	--	--	±10	μA
Additional Quiescent Supply Current Per Input Pin	ΔI <sub>Q</sub>	V <sub>CC</sub> =3 ~ 5.5V, One input at V <sub>CC</sub> -0.6V, Other inputs at V <sub>CC</sub> or GND	--	5	500	--	--	500	μA

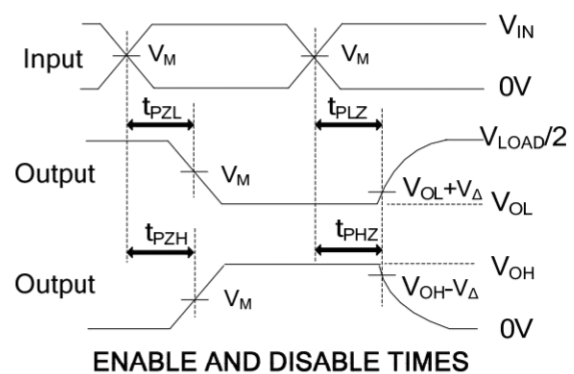
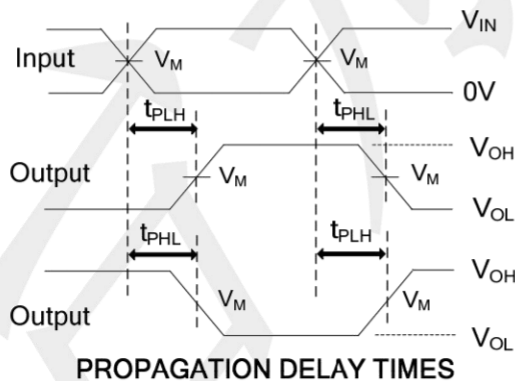
**SWITCHING CHARACTERISTICS** ( unless otherwise specified)

PARAMETER	SYMBOL	TEST Conditions		TA=25°C			TA=-40°C~+125°C			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
Propagation Delay From Input A to Output Y	t <sub>PLH</sub> / t <sub>PHL</sub>	CL=30pF	V <sub>CC</sub> =1.8±0.15V, R <sub>L</sub> =1KΩ	1	12	19	--	--	21	nS
			V <sub>CC</sub> =2.5±0.2V, R <sub>L</sub> =500Ω	0.5	8	15	--	--	17	nS
	RL=500Ω	V <sub>CC</sub> =2.7V	0.5	6	12	--	--	14	nS	
		V <sub>CC</sub> =3.3±0.3V	0.5	5	9	--	--	11	nS	
		V <sub>CC</sub> =5±0.5V	0.5	3	7	--	--	9	nS	
3-State Output Enable Time From Input OE to Output Y	t <sub>PZH</sub> / t <sub>PZL</sub>	CL=30pF	V <sub>CC</sub> =1.8±0.15V, R <sub>L</sub> =1KΩ	1	10	19	--	--	21	nS
			V <sub>CC</sub> =2.5±0.2V, R <sub>L</sub> =500Ω	0.5	7	15	--	--	17	nS
	RL=500Ω	V <sub>CC</sub> =2.7V	0.5	6	12	--	--	14	nS	
		V <sub>CC</sub> =3.3±0.3V	0.5	5	9	--	--	11	nS	
		V <sub>CC</sub> =5±0.5V	0.5	4	7	--	--	9	nS	
3-State Output Disable Time From Input OE to Output Y	t <sub>PLZ</sub> / t <sub>PHZ</sub>	CL=30pF	V <sub>CC</sub> =1.8±0.15V, R <sub>L</sub> =1KΩ	1	5	10	--	--	12	nS
			V <sub>CC</sub> =2.5±0.2V, R <sub>L</sub> =500Ω	0.5	4	8	--	--	10	nS
	RL=500Ω	V <sub>CC</sub> =2.7V	0.5	4	7	--	--	9	nS	
		V <sub>CC</sub> =3.3±0.3V	0.5	3	6	--	--	8	nS	
		V <sub>CC</sub> =5±0.5V	0.5	3	5	--	--	7	nS	

**TEST CIRCUIT AND WAVEFORMS**



TEST	S	INPUTS		V <sub>M</sub>	V <sub>LOAD</sub>	V <sub>Δ</sub>	C <sub>L</sub>	R <sub>L</sub>	
		V <sub>CC</sub>	V <sub>IN</sub>						t <sub>ri</sub> , t <sub>f</sub>
t <sub>PLH</sub> /t <sub>PHL</sub>	Open	1.8V±0.15V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	2 x V <sub>CC</sub>	0.15V	30pF	1KΩ
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND	2.5V±0.2V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	2 x V <sub>CC</sub>	0.15V	30pF	500Ω
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>	2.7V	2.7V	≤2.5ns	1.5V	6V	0.3V	50pF	500Ω
		3.3V±0.3V	2.7V	≤2.5ns	1.5V	6V	0.3V	50pF	500Ω
		5V±0.5V	V <sub>CC</sub>	≤2.5ns	V <sub>CC</sub> /2	2 x V <sub>CC</sub>	0.3V	50pF	500Ω



Note: C<sub>L</sub> includes probe and jig capacitance.

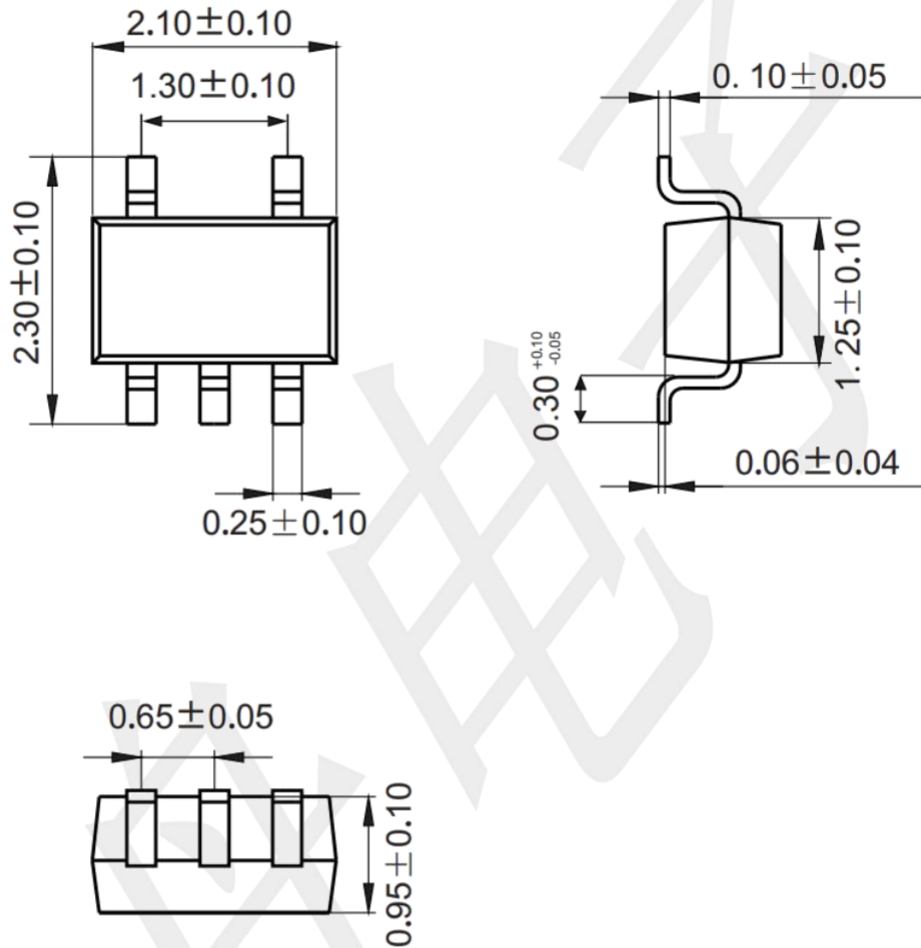
All input pulses are supplied by generators having the following characteristics: P<sub>RR</sub> ≤10MHz, Z<sub>O</sub> = 50Ω.

Notes: 1. C<sub>L</sub> includes probe and jig capacitance.

2. All input pulses are supplied by generators having the following characteristics: P<sub>RR</sub> ≤10MHz, Z<sub>O</sub> = 50Ω.

**Package informantion**

SOT353 (Unit: mm)



**Mounting Pad Layout (unit: mm)**

